# TOSHIBA

TOSHIBA Photocoupler IRED & Photo-Transistor

# TLP626, TLP626-2, TLP626-4

Programmable Controllers AC / DC-Input Module Telecommunication

The TOSHIBA TLP626, -2 and -4 consist of two infrared emitting diodes connected in inverse parallel, optically coupled to a photo-transistor. The TLP626-2 offers two isolated channels in an eight lead plastic DIP, while the TLP626-4 provides four isolated channels in a sixteen plastic DIP.

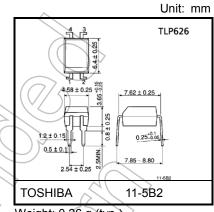
- Collector-emitter voltage: 55 V (min)
- Isolation voltage: 5000 Vrms (min)
- UL-recognized: UL 1577, File No.E67349
- cUL-recognized: CSA Component Acceptance Service No.5A
  - File No.E67349
- VDE-approved: EN 60747-5-5 (Note 1)

Note 1: When a VDE approved type is needed please designate the **Option(D4)**.

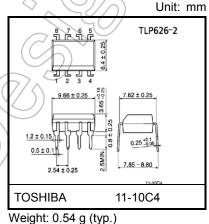
urrent transfer	ratio			
	Curre	ent Transfer Ra	tio (min)	
Classification (Note 1)	Ta =	25°C	Ta = -25 to 75℃	Marking of Classification
	I <sub>F</sub> = ±1mA V <sub>CE</sub> = 0.5V	IF = ±0.5mA V <sub>CE</sub> = 1.5V	I <sub>F</sub> = ±1mA V <sub>CE</sub> = 0.5V	
Rank BV	200%	100%	100%	BV
Standard	100%	50%	50%	BV, blank
	Classification (Note 1) Rank BV	Classification (Note 1) Rank BV	Classification (Note 1) Rank BV Current Transfer Ra Ta = 25°C IF = ±1mA VCE = 0.5V VCE = 1.5V Current Transfer Ra IF = ±0.5mA VCE = 1.5V 100%	$\begin{tabular}{ c c c c c c } \hline Current Transfer Ratio (min) \\ \hline Classification (Note 1) \\ \hline IF = \pm 1mA \\ V_{CE} = 0.5V \\ \hline V_{CE} = 1.5V \\ \hline V_{CE} = 1.5V \\ \hline V_{CE} = 0.5V \\ \hline Rank BV \\ \hline 200\% \\ \hline 100\% \\ \hline 100\% \\ \hline \end{tabular}$

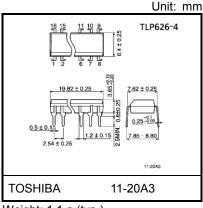
Note 1: Only TLP626 is applied to BV rank items. Note: Application type name for certification test, please use standard product type name, i.e.

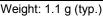
(TLP626(BV): TLP626



Weight: 0.26 g (typ.)

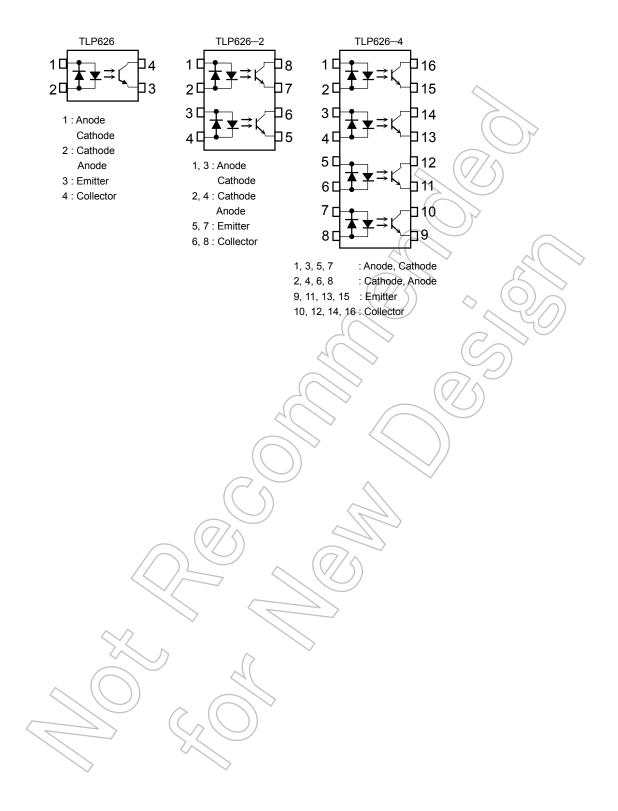






Start of commercial production 1984-04

#### Pin Configuration (top view)



#### Absolute Maximum Ratings (Ta = 25°C)

				Rati	ing		
	Characteristic		Symbol	TLP626	TLP626-2 TLP626-4	Unit	
	Forward current		IF	60	50	mA	
	Forward current derating		ΔI <sub>F</sub> / °C	-0.7 (Ta ≥ 39°C)	-0.5 (Ta ≥ 25°C)	mA / °C	
Q	Pulse forward current		IFP	1 (100µs pul	se,100pps)	А	
Ц	Diode Power dissipation		PD	100	70	mW	
	Diode Power dissipation derating		ΔP <sub>D</sub> /°C	-1.2 (Ta ≥ 39°C)	-0.7 (Ta ≥ 25°C)	mW / °C	
	Junction temperature		Tj	12	125		
	Collector-emitter voltage Emitter-collector voltage		VCEO	55		V	
			V <sub>ECO</sub>	7		V	
tor	Collector current		lc	50		mA	
Detector	Collector power dissipation (1 circuit)		Pc	150	100	mW	
]	Collector power dissipation derating $(Ta \ge 25^{\circ}C, 1 \text{ circuit})$		ΔPc/°C	-1.5		mW / °C	
	Junction temperature		Ţ	12	5	°C	
Sto	rage temperature range	.(	T <sub>stg</sub>	-55 to 125		°C	
Ope	erating temperature range	$\langle$	Popr	-55 to 100		°C	
Lead soldering temperature		T <sub>sol</sub>	260 (10 s)		°C		
Tota	al package power dissipation (1 circuit)		Рт	250	150	mW	
Tota	al package power dissipation derating (Ta $\geq$ :	25°C, 1 circuit)	ΔΡτ/°C	-2.5	-1.5	mW / °C	
Isol	ation voltage	(Note 1)	BVs	5000 (AC, 60 s	s, R.H.≤60 %)	Vrms	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

## **Recommended Operating Conditions**

Characteristic	Symbol	Min	Тур.	Max	Unit
Supply voltage	Vcc	_	5	24	V
Forward current	IF(RMS)	_	1.6	20	mA
Collector current	lc	_	1	10	mA
Operating temperature	T <sub>opr</sub>	-25	_	75	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Note 1: Device considered a two terminal: LED side pins shorted together, and detector side pins shorted together.

**Electrical Characteristics (Ta = 25°C)** 

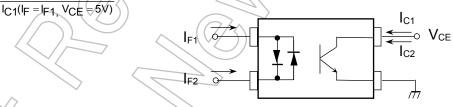
	Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	VF	I <sub>F</sub> = ±10 mA	1.0	1.15	1.3	V
LED	Reverse current	lF	V <sub>F</sub> = ±0.7 V	_	2.5	20	μA
	Capacitance	CT	V = 0 V, f = 1 MHz	-<	60	-	pF
	Collector-emitter breakdown voltage	V(BR)CEO	IC = 0.5 mA	55		1	V
r	Emitter-collector breakdown voltage	V(BR)ECO	IE = 0.1 mA	7		)~	V
Detector	Collector dark current	ICEO	V <sub>CE</sub> = 24 V	$\overline{(7)}$	10	100	nA
ð			V <sub>CE</sub> = 24 V, Ta = 85° C	Y),	)2	50	μA
	Capacitance collector to emitter	CCE	V = 0 V, f = 1 MHz		12	_	pF

#### **Coupled Electrical Characteristics (Ta = 25°C)**

	•		$\searrow$		1	$\geq$
Characteristic	Symbol	Test Condition	Min	Тур	Max	Unit
Current transfer ratio	IC / IF	$I_F = \pm 1 \text{ mA}, V_{CE} = 0.5 \text{ V}$ rank BV(Note 2)	100 200	Nr6	1200 1200	%
Low input CTR	IC / IF(low)	$I_F = \pm 0.5 \text{ mA}, V_{CE} = 1.5 \text{ V}$ rank BV(Note 2)	50 100	$\widehat{\mathcal{D}}$		%
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	$I_C = 0.5 \text{ mA}, I_F = \pm 1 \text{ mA}$ $I_C = 1 \text{ mA}, I_F = \pm 1 \text{ mA}$ rank BV(Note 2)	Ø	— 0.2	0.4	V
Off-state collector current	Ic(off)	$V_{\rm F} = \pm 0.7 \text{ V}, \text{ V}_{\rm CE} = 24 \text{ V}$	))=	1	0.4 10	μA
CTR symmetry (Note 1)	I <sub>C</sub> (ratio)	1 <sub>C</sub> (I <sub>F</sub> = -1 mA) / I <sub>C</sub> (I <sub>F</sub> = 1 mA)	0.5	—	2	_

Note 1

IC(ratio) =  $\frac{I_{C2}(I_F = I_{F2}, V_{CE} = 5V)}{I_{C2}(I_F = I_{F2}, V_{CE} = 5V)}$ 



Note 2: Only TLP626 is applied to BV rank items.

#### Coupled Electrical Characteristics (Ta = -25 to 75°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Current transfer ratio		I <sub>F</sub> = 1 mA, V <sub>CE</sub> = 0.5 V	50	_	—	%
	IC / IF	rank BV(Note 1)	100	_	_	
Low input CTR		IF = 0.5 mA, V <sub>CE</sub> = 1.5 V	_	50		%
	IC / IF(low)	rank BV(Note 1)		100		70

Note 1: Only TLP626 is applied to BV rank items.

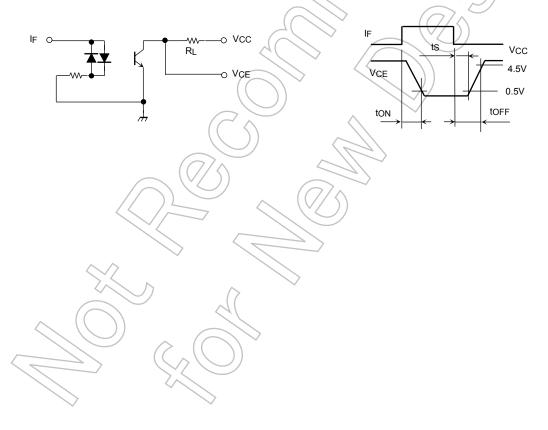
#### Isolation Characteristics (Ta = 25°C)

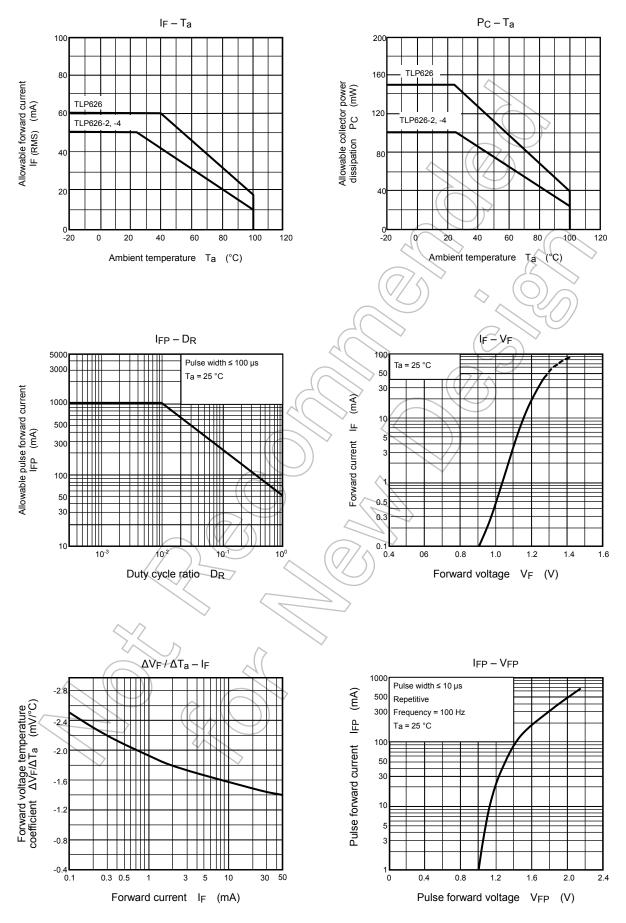
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance input to output	CS	V <sub>S</sub> = 0 V, f = 1 MHz	_	0.8	_	pF
Isolation resistance	Rs	V <sub>S</sub> = 500 V, R.H.≤60 %	5×10 <sup>10</sup>	10 <sup>14</sup>	_	Ω
Isolation voltage	BVs	AC, 60 s	5000	/	_	Vrms

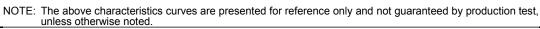
#### Switching Characteristics (Ta = 25°C)

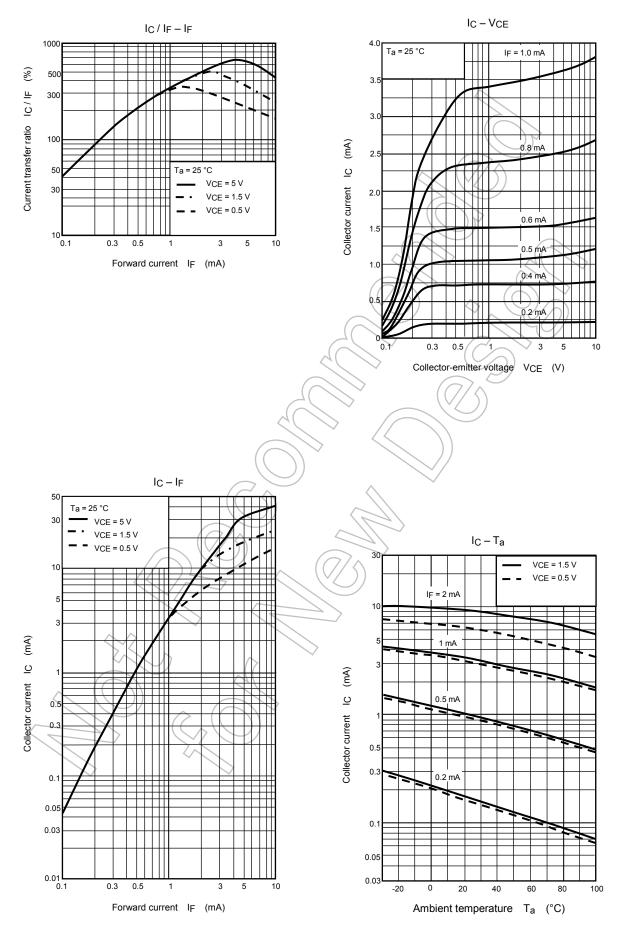
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Rise time	tr	$V_{CC} = 10 \text{ V}, \text{ I}_{C} = 2 \text{ mA}$ $R_L = 100 \Omega$		8	Ι	
Fall time	tf		J.	8	_	
Turn-on time	t <sub>on</sub>		-	10	μ:	μs
Turn-off time	toff		~ _	8	L'	$\searrow$
Turn-on time	ton	(7/5)	_	10	1	
Storage time	ts	RL = 4.7 kΩ (Fig.1) V <sub>CC</sub> = 5 V, $I_F$ = ±1.6 mA		50	$\mathcal{I}_{\mathcal{A}})$	μs
Turn-off time	toff		-	300	2	

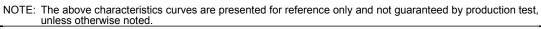
Fig. 1: Switching operating conditions



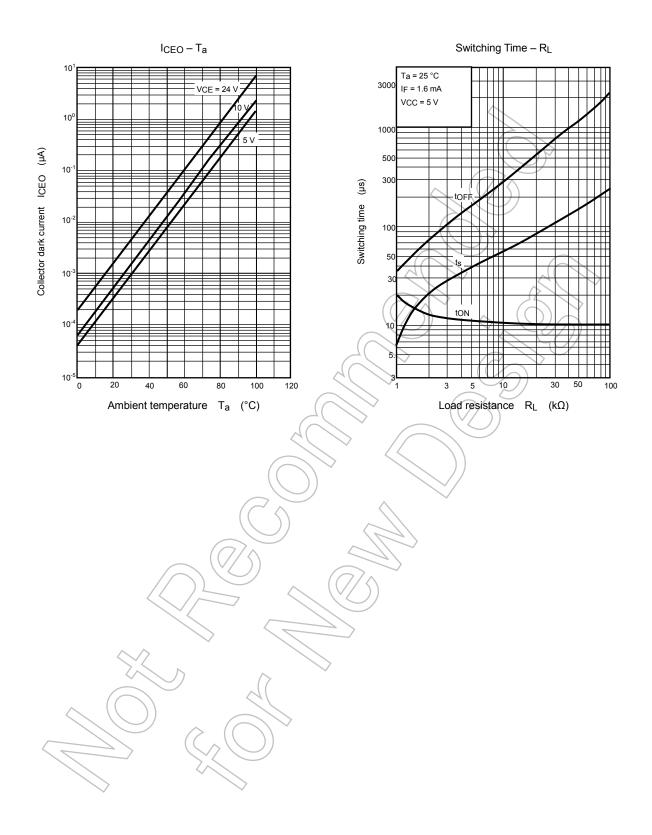








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NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

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